HARP

PC123XNNSZ0F Series

DIP 4pin Reinforced Insulation Type Photocoupler



Description

PC123XNNSZOF Series contains an IRED optically coupled to a phototransistor.

It is packaged in a 4-pin DIP, available in wide-lead spacing option and SMT gullwing lead-form option.

Input-output isolation voltage(rms) is 5kV.

CTR is 50% to 400% at input current of 5mA

Features

- 1.4-pin DIP package
- 2. Double transfer mold package (Ideal for Flow Soldering)
- 3. Current transfer ratio (CTR : MIN. 50% at I_F=5 mA, $V_{CE}=5V$)
- 4. Several CTR ranks available
- 5. Reinforced insulation type (Isolation distance : MIN. 0.4mm)
- 6. Long creepage distance type (wide lead-form type only : MIN. 8mm)
- 7. High isolation voltage between input and output $(V_{iso}(rms) : 5kV)$
- 8. RoHS directive compliant

■Agency approvals/Compliance

- 1. Recognized by UL1577 (Double protection isolation), file No. E64380 (as model No. PC123)
- 2. Approved by BSI, BS-EN60065, file No. 7087, BS-EN60950 file No. 7409, (as model No. PC123)
- 3. Approved by SEMKO, EN60065, EN60950, (as model No. PC123)
- 4. Approved by DEMKO, EN60065, EN60950, (as model No. PC123)
- 5. Approved by NEMKO, EN60065, EN60950, (as model No. PC123)
- 6. Approved by FIMKO, EN60065, EN60950, (as model No. PC123)
- 7. Recognized by CSA file No. CA95323, (as model No. PC123)
- 8. Approved by VDE, DIN EN60747-5-2(*) (as an option), file No. 40008087 (as model No. PC123)
- 9. Package resin : UL flammability grade (94V 0)

(*) DIN EN60747-5-2 : successor standard of DIN VDE0884.

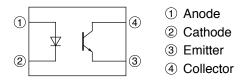
■Applications

- 1. I/O isolation for MCUs (Micro Controller Units)
- 2. Noise suppression in switching circuits
- 3. Signal transmission between circuits of different potentials and impedances
- 4. Over voltage detection

In the absence of confirmation by device specification sheets, SHARP takes no responsibility for any defects that may occur in equipment using any SHARP devices shown in catalogs, data books, etc. Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device.

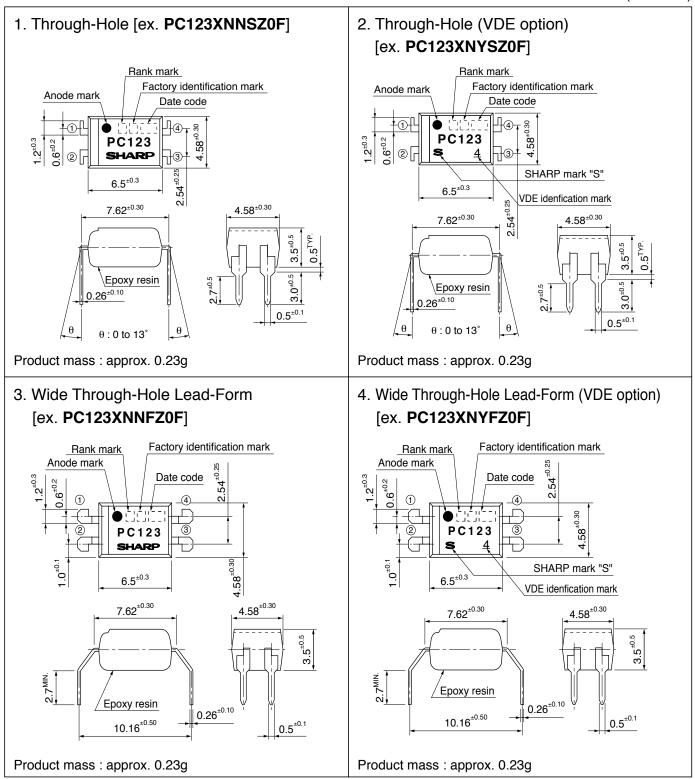


Internal Connection Diagram

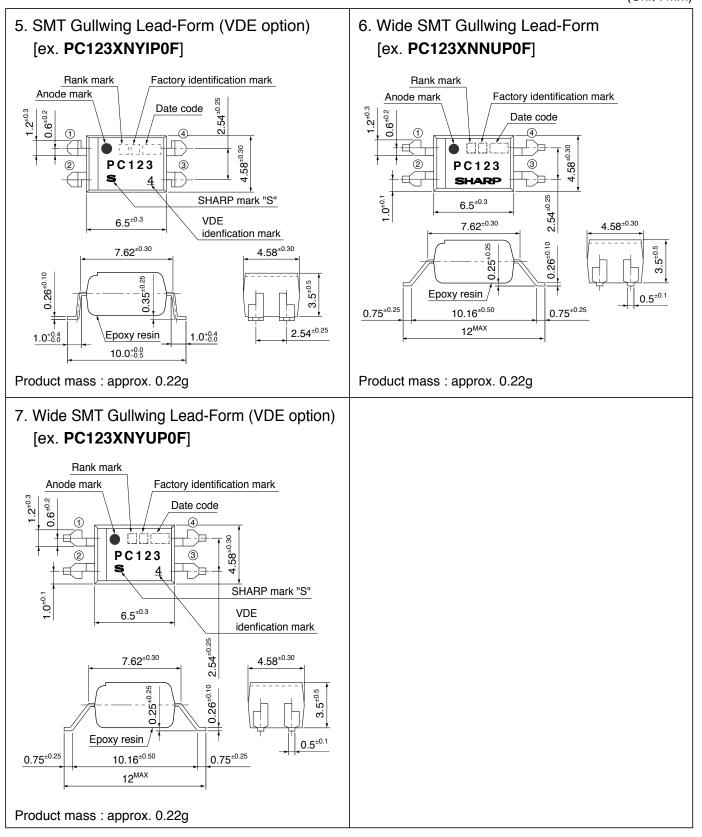


■ Outline Dimensions

(Unit : mm)



(Unit : mm)



Date code (2 digit)

	1st o	digit		2nd digit		
	Year of p	roduction		Month of production		
A.D.	Mark	A.D.	Mark	Month	Mark	
1990	А	2002	Р	January	1	
1991	В	2003	R	February	2	
1992	С	2004	S	March	3	
1993	D	2005	Т	April	4	
1994	Е	2006	U	May	5	
1995	F	2007	V	June	6	
1996	Н	2008	W	July	7	
1997	J	2009	Х	August	8	
1998	K	2010	А	September	9	
1999	L	2011	В	October	0	
2000	М	2012	С	November	N	
2001	N	:	:	December	D	

repeats in a 20 year cycle

Factory identification mark and Plating material

Factory identification Mark	Country of origin	Plating material		
no mark	Isman			
	Japan	SnCu (Cu : TYP. 2%)		
or	Indonesia	SnBi (Bi : TYP. 2%)		
or 🔪	China	SnCu (Cu : TYP. 2%)*		
	China	SnCu (Cu : TYP. 2%)		

* Up to Date code "T4" (April 2005), SnBi (Bi : TYP. 2%).

** This factory marking is for identification purpose only.

Please contact the local SHARP sales representative to see the actural status of the production.

Rank mark

Refer to the Model Line-up table.

■ Absolute Maximum Ratings

Abs	$(T_a=25^{\circ}C)$			
	Parameter	Symbol	Rating	Unit
	Forward current	I _F	50	mA
Input	*1 Peak forward current	I _{FM}	1	А
Input	Reverse voltage	V _R	6	V
	Power dissipation	Р	70	mW
	Collector-emitter voltage	V _{CEO}	70	V
Outrout	Emitter-collector voltage	V _{ECO}	6	V
Output	Collector current	I _C	50	mA
	Collector power dissipation	P _C	150	mW
Total	power dissipation	P _{tot}	200	mW
*2 Isolat	ion voltage	V _{iso} (rms)	5	kV
Operating temperature		T _{opr}	-30 to +100	°C
Stora	ge temperature	T _{stg}	-55 to +125	°C
*2 Solde	ering temperature	T _{sol}	260	°C

*1 Pulse width≤100ms, Duty ratio : 0.001

*2 40 to 60%RH, AC for 1 minute, f = 60Hz

*3 For 10s

■ Electro-optical Characteristics

 $(T_a=25^{\circ}C)$

	Parameter		Symbol	Condition	MIN.	TYP.	MAX.	Unit
	Forward voltage		V _F	$I_{F}=20mA$	_	1.2	1.4	V
Input	Reverse current		I _R	V _R =4V	_	_	10	μΑ
-	Terminal capacitance		Ct	V=0, f=1kHz	_	30	250	pF
	Collector dark current		I _{CEO}	V _{CE} =50V, I _F =0	_	-	100	nA
Output	Collector-emitter breakdown voltage		BV _{CEO}	$I_{C}=0.1 \text{mA}, I_{F}=0$	70	-	_	V
	Emitter-collector breakdown voltage		BV _{ECO}	$I_{E}=10\mu A, I_{F}=0$	6	-	-	nA
	Collector current		I _C	$I_{F}=5mA, V_{CE}=5V$	2.5	-	20	mA
	Collector-emitter saturation	on voltage	V _{CE(sat)}	$I_F=20mA, I_C=1mA$	-	0.1	0.2	V
Transfer	Isolation resistance		R _{ISO}	DC500V, 40 to 60%RH	5×10 ¹⁰	1×10 ¹¹	-	Ω
charac-	0 1		C _f	V=0, f=1MHz	-	0.6	1	pF
teristics			f _C	$V_{CE}=5V, I_{C}=2mA, R_{L}=100\Omega, -3dB$	-	80	-	kHz
	D	Rise time	t _r	V 2V L 2m A D 1000	_	4	18	μs
	Response time	Fall time	t _f	$V_{CE}=2V, I_C=2mA, R_L=100\Omega$	_	3	18	μs



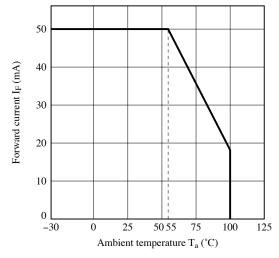
■ Model Line-up

Lead Form	Through-Hole Wide Through-Hole				I [m A]	
Package		Sle	eve			$I_{C}[mA]$ ($I_{F}=5mA$,
I ackage		100pcs	sleeve		Rank mark	$V_{CE}=5V,$
DIN		Approved		Approved		$T_a=25^{\circ}C$
EN60747-5-2				ra-23 C)		
	PC123XNNSZ0F	PC123XNYSZ0F	PC123XNNFZ0F	PC123XNYFZ0F	With or without	2.5 to 20
	PC123X1NSZ0F	PC123X1YSZ0F	PC123X1NFZ0F	PC123X1YFZ0F	L	2.5 to 7.5
Model No.	PC123X2NSZ0F	PC123X2YSZ0F	PC123X2NFZ0F	PC123X2YFZ0F	М	5 to 12.5
	PC123X5NSZ0F	PC123X5YSZ0F	PC123X5NFZ0F	PC123X5YFZ0F	N	10 to 20
	PC123X8NSZ0F	PC123X8YSZ0F	PC123X8NFZ0F	PC123X8YFZ0F	Е	5 to 10

Lead Form	SMT G	SMT Gullwing Wide SMT Gullwing			I [m A]	
Daalaaga		Tap	oing			$I_{C}[mA]$ ($I_{F}=5mA$,
Package		2 000p	ocs/reel		Rank mark	$V_{CE}=5V,$
DIN EN60747-5-2		Approved		Approved		$T_a=25^{\circ}C$
		PC123XNYIP0F	PC123XNNUP0F	PC123XNYUP0F	With or without	2.5 to 20
		PC123X1YIP0F	PC123X1NUP0F	PC123X1YUP0F	L	2.5 to 7.5
Model No.		PC123X2YIP0F	PC123X2NUP0F	PC123X2YUP0F	М	5 to 12.5
		PC123X5YIP0F	PC123X5NUP0F	PC123X5YUP0F	N	10 to 20
		PC123X8YIP0F	PC123X8NUP0F	PC123X8YUP0F	Е	5 to 10

Please contact a local SHARP sales representative to inquire about production status.

Fig.1 Forward Current vs. Ambient Temperature





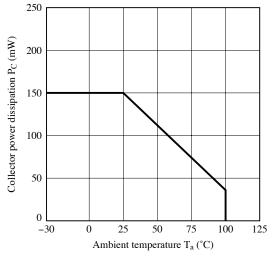


Fig.5 Peak Forward Current vs. Duty Ratio

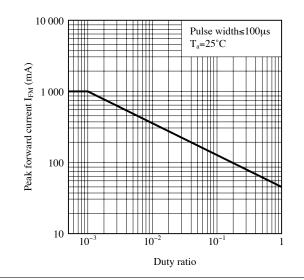


Fig.2 Diode Power Dissipation vs. Ambient Temperature

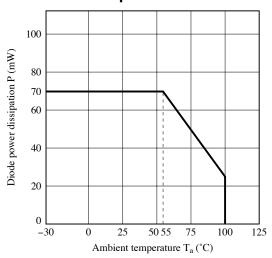


Fig.4 Total Power Dissipation vs. Ambient Temperature

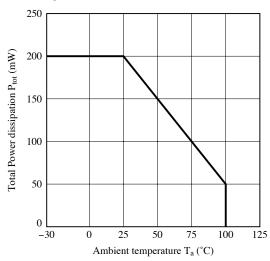


Fig.6 Forward Current vs. Forward Voltage

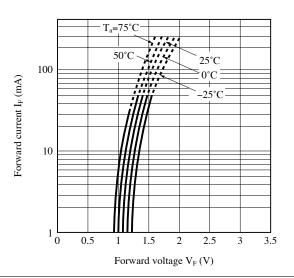
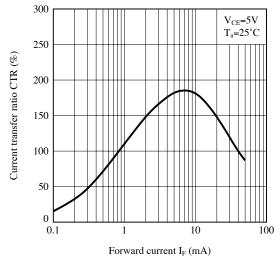


Fig.7 Current Transfer Ratio vs. Forward Current





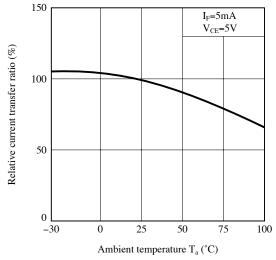


Fig.11 Collector Dark Current vs. Ambient Temperature

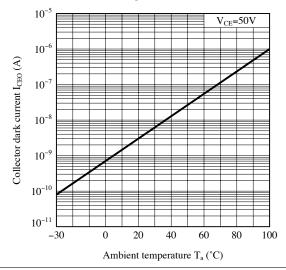


Fig.8 Collector Current vs. Collector-emitter Voltage

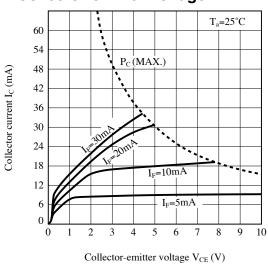


Fig.10 Collector - emitter Saturation Voltage vs. Ambient Temperature

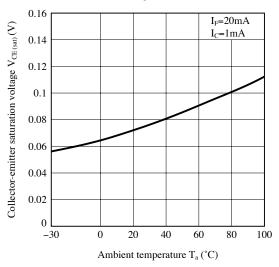


Fig.12 Response Time vs. Load Resistance

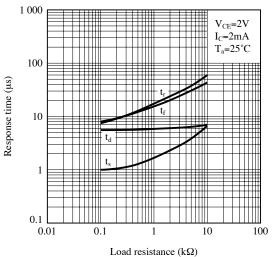




Fig.13 Test Circuit for Response Time

Input R_D R_L Output W_{CE} U_{CE} $U_$

Please refer to the conditions in Fig.12.

Fig.14 Frequency Response

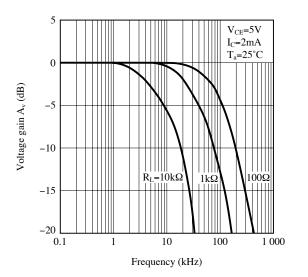
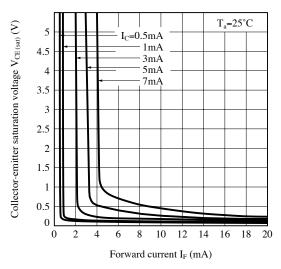


Fig.15 Collector-emitter Saturation Voltage vs. Forward Current



Remarks : Please be aware that all data in the graph are just for reference and not for guarantee.



■ Design Considerations

• Design guide

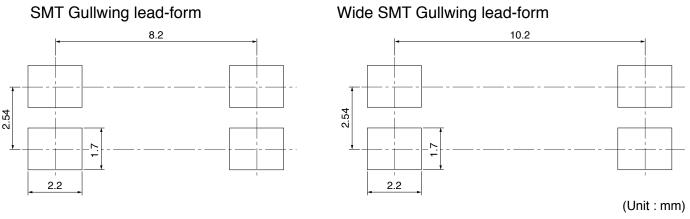
While operating at $I_F < 1mA$, CTR variation may increase. Please make design considering this fact.

This product is not designed against irradiation and incorporates non-coherent IRED.

Degradation

In general, the emission of the IRED used in photocouplers will degrade over time. In the case of long term operation, please take the general IRED degradation (50% degradation over 5 years) into the design consideration.

Recommended foot print (reference)



☆ For additional design assistance, please review our corresponding Optoelectronic Application Notes.

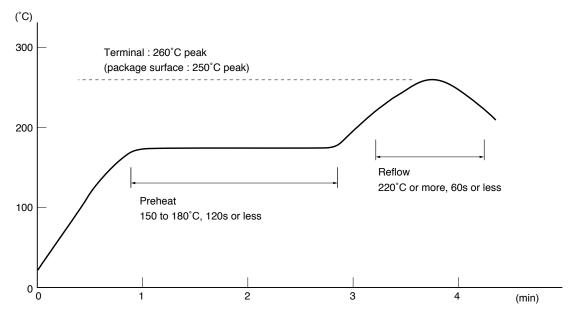


Manufacturing Guidelines

Soldering Method

Reflow Soldering :

Reflow soldering should follow the temperature profile shown below. Soldering should not exceed the curve of temperature profile and time. Please don't solder more than twice.



Flow Soldering :

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 270°C and within 10s. Preheating is within the bounds of 100 to 150°C and 30 to 80s. Please don't solder more than twice.

Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400°C. Please don't solder more than twice

Other notice

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.



• Cleaning instructions

Solvent cleaning :

Solvent temperature should be 45°C or below. Immersion time should be 3 minutes or less.

Ultrasonic cleaning :

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.

Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

Recommended solvent materials :

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol.

In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

Presence of ODC

This product shall not contain the following materials. And they are not used in the production process for this product. Regulation substances : CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBB and PBDE are not used in this product at all.

This product shall not contain the following materials banned in the RoHS Directive (2002/95/EC).
•Lead, Mercury, Cadmium, Hexavalent chromium, Polybrominated biphenyls (PBB), Polybrominated diphenyl ethers (PBDE).

Package specification

• Sleeve package

1. Through-Hole

Package materials

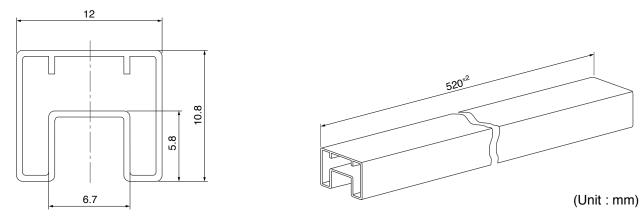
Sleeve : HIPS (with anti-static material) Stopper : Styrene-Elastomer

Package method

MAX. 100pcs of products shall be packaged in a sleeve. Both ends shall be closed by tabbed and tabless stoppers.

The product shall be arranged in the sleeve with its anode mark on the tabless stopper side. MAX. 20 sleeves in one case.

Sleeve outline dimensions



2. Wide Through-Hole

Package materials

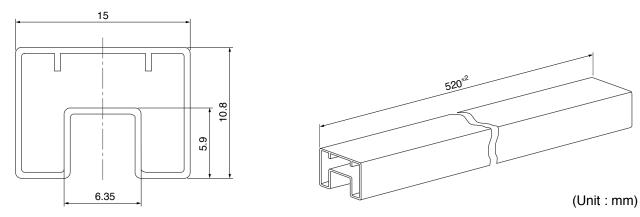
Sleeve : HIPS (with anti-static material) Stopper : Styrene-Elastomer

Package method

MAX. 100pcs of products shall be packaged in a sleeve. Both ends shall be closed by tabbed and tabless stoppers.

The product shall be arranged in the sleeve with its anode mark on the tabless stopper side. MAX. 20 sleeves in one case.

Sleeve outline dimensions



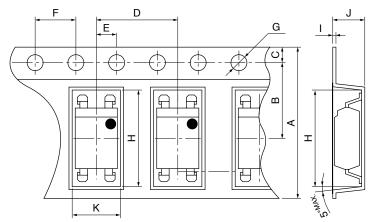


• Tape and Reel package

1. SMT Gullwing

Package materials Carrier tape : PS Cover tape : PET (three layer system) Reel : PS

Carrier tape structure and Dimensions

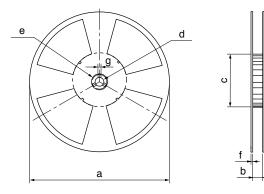


Dimensior	ns List	
Δ	В	C

(Unit : mm)

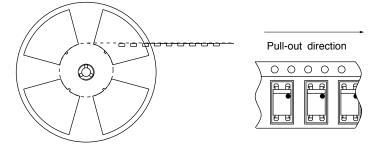
А	В	С	D	Е	F	G
16.0 ^{±0.3}	$7.5^{\pm0.1}$	$1.75^{\pm 0.10}$	$8.0^{\pm0.1}$	$2.0^{\pm 0.1}$	$4.0^{\pm 0.1}$	φ1.5 <u>+8:</u>
Н	Ι	J	K			
$10.4^{\pm 0.1}$	$0.40^{\pm 0.05}$	$4.2^{\pm 0.1}$	$5.1^{\pm 0.1}$			

Reel structure and Dimensions



Dimensio	ns List	(Unit : mm)			
а	b	с	d		
ф330	$17.5^{\pm 1.5}$	$\phi 100^{\pm 1}$	φ13.0 ^{±0.5}		
e	f	g			
φ23 ^{±1}	$2.0^{\pm 0.5}$	$2.0^{\pm 0.5}$			

Direction of product insertion



[Packing : 2 000pcs/reel]

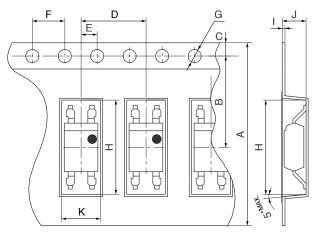


2. Wide SMT Gullwing

Package materials

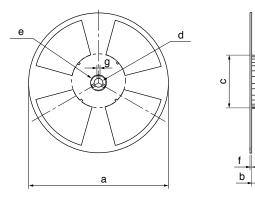
Carrier tape : PS Cover tape : PET (three layer system) Reel : PS

Carrier tape structure and Dimensions



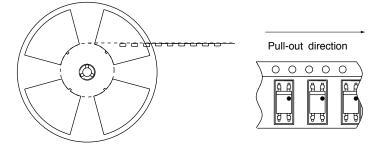
Dimensions List (Unit : mm)								
А	В	С	D	Е	F	G		
24.0 ^{±0.3}	$11.5^{\pm0.1}$	$1.75^{\pm 0.10}$	$8.0^{\pm 0.1}$	$2.0^{\pm 0.1}$	$4.0^{\pm 0.1}$	$\phi 1.5^{+0.1}_{-0.0}$		
Н	Ι	J	K					
$12.4^{\pm 0.1}$	$0.40^{\pm 0.05}$	$4.1^{\pm 0.1}$	$5.1^{\pm 0.1}$					

Reel structure and Dimensions



Dimensio	ns List	(Unit : mm)		
а	b	с	d	
ф 330	$25.5^{\pm 1.5}$	$\phi 100^{\pm 1}$	φ13.0 ^{±0.5}	
e	f	g		
φ23 ^{±1}	$2.0^{\pm 0.5}$	$2.0^{\pm 0.5}$		

Direction of product insertion



[Packing : 2 000pcs/reel]

SHARP

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(i) The devices in this publication are designed for use in general electronic equipment designs such as:

- --- Personal computers
- --- Office automation equipment
- --- Telecommunication equipment [terminal]
- --- Test and measurement equipment
- --- Industrial control
- --- Audio visual equipment
- --- Consumer electronics

(ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection with equipment that requires higher reliability such as:

- --- Transportation control and safety equipment (i.e., aircraft, trains, automobiles, etc.)
- --- Traffic signals
- --- Gas leakage sensor breakers
- --- Alarm equipment
- --- Various safety devices, etc.

(iii) SHARP devices shall not be used for or in connection with equipment that requires an extremely high level of reliability and safety such as:

- --- Space applications
- --- Telecommunication equipment [trunk lines]
- --- Nuclear power control equipment
- --- Medical and other life support equipment (e.g., scuba).

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